

SOT-23



Pin Definition:

1. Gate
2. Source
3. Drain

PRODUCT SUMMARY

V_{DS} (V)	$R_{DS(on)}$ (m Ω)	I_D (A)
-20	39 @ $V_{GS} = -4.5V$	-4.7
	52 @ $V_{GS} = -2.5V$	-4.1
	68 @ $V_{GS} = -1.8V$	-2.0

Features

- Advance Trench Process Technology
- High Density Cell Design for Ultra Low On-resistance

Application

- Load Switch
- PA Switch

Ordering Information

Part No.	Package	Packing
TSM2323CX RFG	SOT-23	3Kpcs / 7" Reel

Note: "G" denote for Green Product

Absolute Maximum Rating ($T_a = 25^\circ C$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V_{DS}	-20	V
Gate-Source Voltage	V_{GS}	± 8	V
Continuous Drain Current, V_{GS} @ 4.5V.	I_D	-4.7	A
Pulsed Drain Current, V_{GS} @ 4.5V	I_{DM}	-20	A
Continuous Source Current (Diode Conduction) ^{a,b}	I_S	-1.0	A
Maximum Power Dissipation	P_D	$T_a = 25^\circ C$	1.25
		$T_a = 70^\circ C$	0.8
Operating Junction Temperature	T_J	+150	$^\circ C$
Operating Junction and Storage Temperature Range	T_J, T_{STG}	- 55 to +150	$^\circ C$

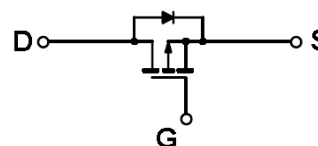
Thermal Performance

Parameter	Symbol	Limit	Unit
Junction to Case Thermal Resistance	$R_{\theta_{JC}}$	75	$^\circ C/W$
Junction to Ambient Thermal Resistance (PCB mounted)	$R_{\theta_{JA}}$	120	$^\circ C/W$

Notes:

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

Block Diagram



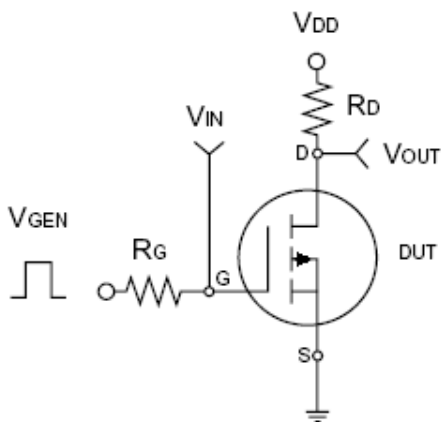
P-Channel MOSFET

Electrical Specifications

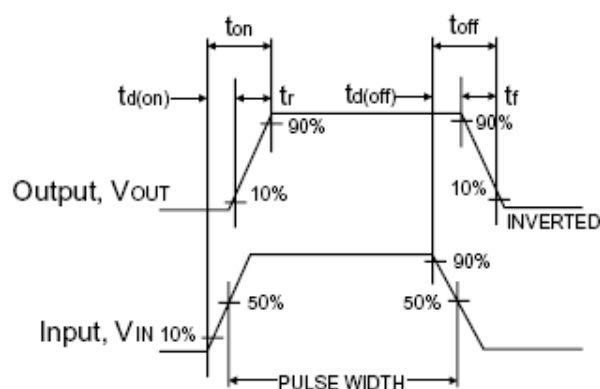
Parameter	Conditions	Symbol	Min	Typ	Max	Unit
Static						
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = -250\mu A$	BV_{DSS}	-20	--	--	V
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = -250\mu A$	$V_{GS(TH)}$	-0.4	--	-1.0	V
Zero Gate Voltage Drain Current	$V_{DS} = -16V, V_{GS} = 0V$	I_{DSS}	--	--	-1.0	μA
Gate Body Leakage	$V_{GS} = \pm 8V, V_{DS} = 0V$	I_{GSS}	--	--	± 100	nA
On-State Drain Current	$V_{DS} \leq -5V, V_{GS} = -4.5V$	$I_{D(ON)}$	-20	--	--	A
Drain-Source On-State Resistance	$V_{GS} = -4.5V, I_D = -4.7A$	$R_{DS(ON)}$	--	31	39	m Ω
	$V_{GS} = -2.5V, I_D = -4.1A$		--	41	52	
	$V_{GS} = -1.8V, I_D = -2.0A$		--	54	68	
Forward Transconductance	$V_{DS} = -5V, I_D = -4.7A$	g_{fs}	--	16	--	S
Diode Forward Voltage	$I_S = -1.0A, V_{GS} = 0V$	V_{SD}	--	-0.7	-1.2	V
Dynamic^b						
Total Gate Charge	$V_{DS} = -10V, I_D = -4.7A, V_{GS} = -4.5V$	Q_g	--	12.5	19	nC
Gate-Source Charge		Q_{gs}	--	1.7	--	
Gate-Drain Charge		Q_{gd}	--	3.3	--	
Input Capacitance	$V_{DS} = -10V, V_{GS} = 0V, f = 1.0MHz$	C_{iss}	--	1020	--	pF
Output Capacitance		C_{oss}	--	191	--	
Reverse Transfer Capacitance		C_{rss}	--	140	--	
Switching^{b,c}						
Turn-On Delay Time	$V_{DD} = -10V, R_L = 10\Omega, I_D = -1A, V_{GEN} = -4.5V, R_G = 6\Omega$	$t_{d(on)}$	--	25	40	nS
Turn-On Rise Time		t_r	--	43	65	
Turn-Off Delay Time		$t_{d(off)}$	--	71	110	
Turn-Off Fall Time		t_f	--	48	75	

Notes:

- a. pulse test: $PW \leq 300\mu S$, duty cycle $\leq 2\%$
- b. Guaranteed by design of component.
- c. Switching time is essentially independent of operating temperature.



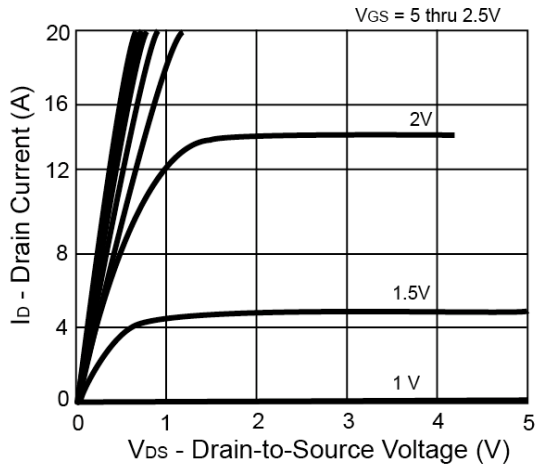
Switching Test Circuit



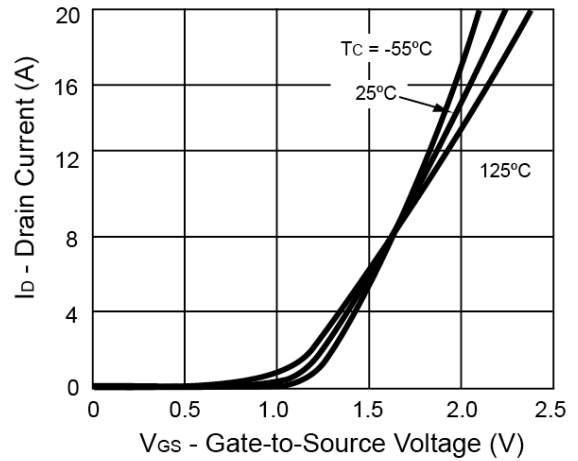
Switchin Waveforms

Electrical Characteristics Curve ($T_a = 25^\circ\text{C}$, unless otherwise noted)

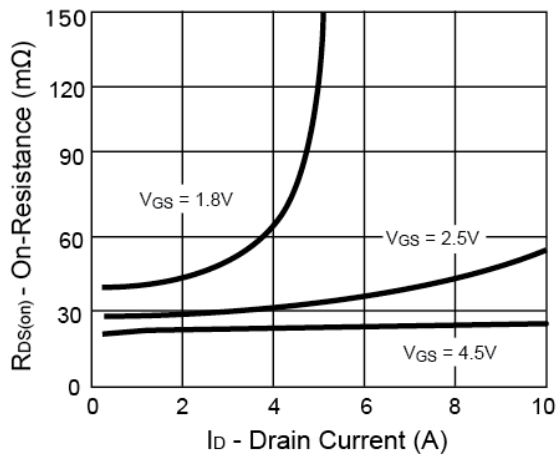
Output Characteristics



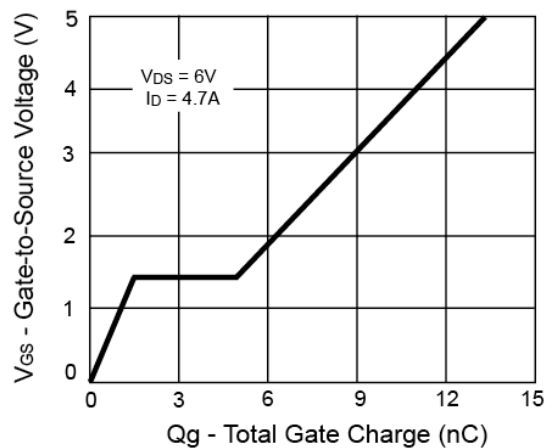
Transfer Characteristics



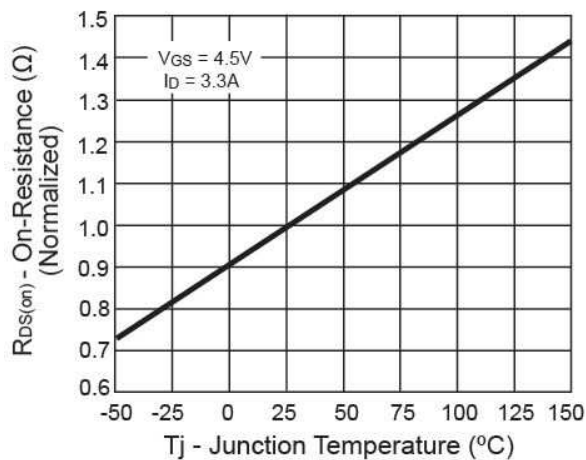
On-Resistance vs. Drain Current



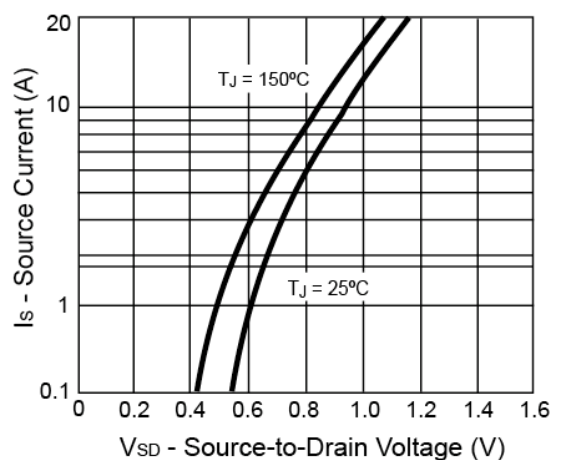
Gate Charge



On-Resistance vs. Junction Temperature

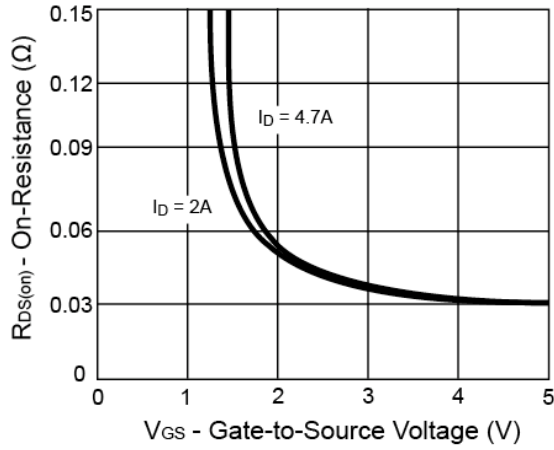


Source-Drain Diode Forward Voltage

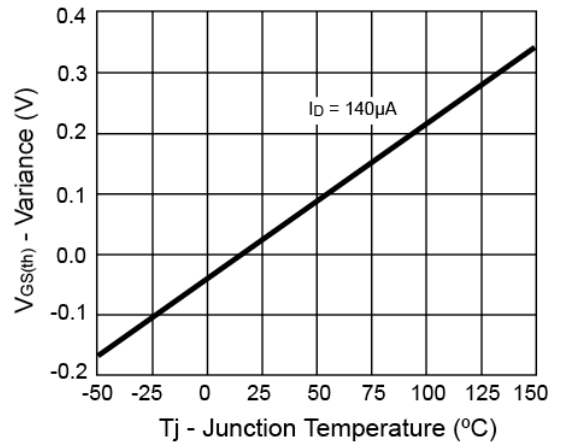


Electrical Characteristics Curve ($T_a = 25^\circ\text{C}$, unless otherwise noted)

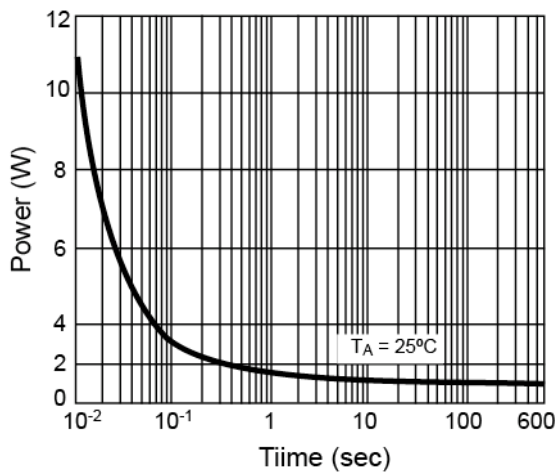
On-Resistance vs. Gate-Source Voltage



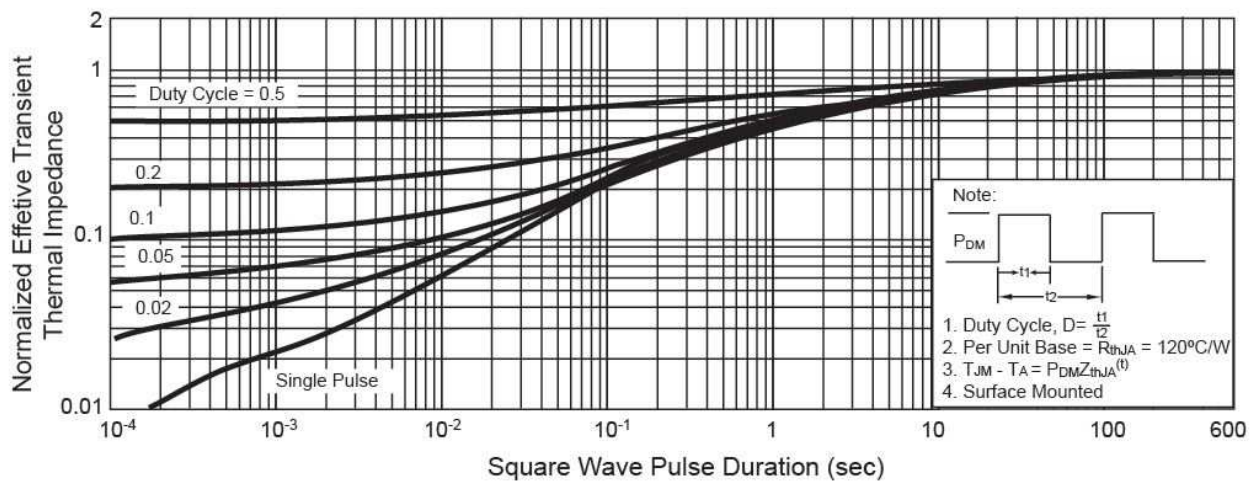
Threshold Voltage



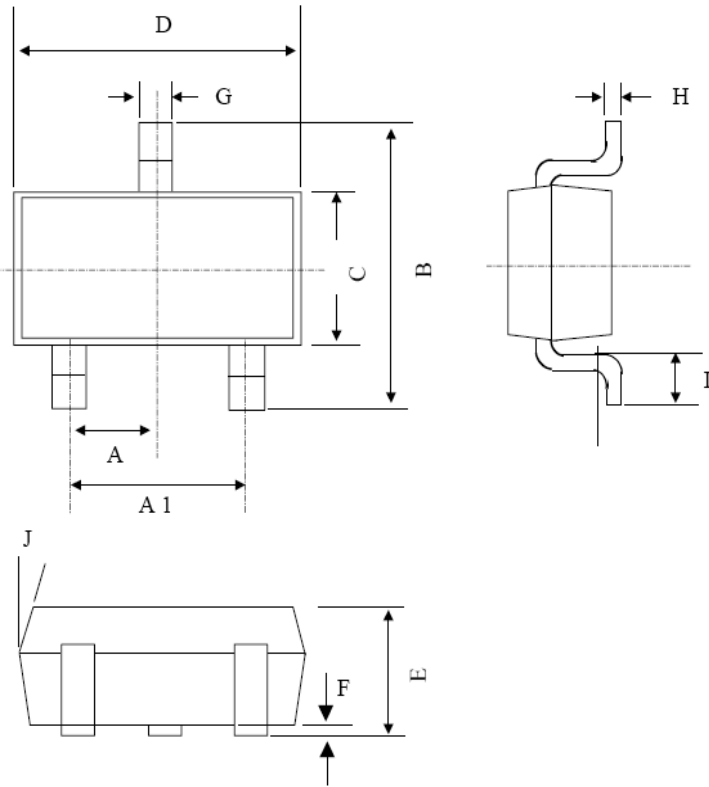
Single Pulse Power



Normalized Thermal Transient Impedance, Junction-to-Ambient

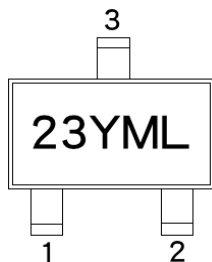


SOT-23 Mechanical Drawing



SOT-23 DIMENSION				
DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX.
A	0.95 BSC		0.037 BSC	
A1	1.9 BSC		0.074 BSC	
B	2.60	3.00	0.102	0.118
C	1.40	1.70	0.055	0.067
D	2.80	3.10	0.110	0.122
E	1.00	1.30	0.039	0.051
F	0.00	0.10	0.000	0.004
G	0.35	0.50	0.014	0.020
H	0.10	0.20	0.004	0.008
I	0.30	0.60	0.012	0.024
J	5°	10°	5°	10°

Marking Diagram



- 23** = Device Code
- Y** = Year Code
- M** = Month Code for Halogen Free Product
 - O** =Jan **P** =Feb **Q** =Mar **R** =Apr
 - S** =May **T** =Jun **U** =Jul **V** =Aug
 - W** =Sep **X** =Oct **Y** =Nov **Z** =Dec
- L** = Lot Code

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